



Patent  
Attorney's Docket No. 030681-280

**UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of )  
Sung-nam LEE et al. ) Group Art Unit: 2811  
Application No.: 09/776,846 ) Examiner: Unknown  
Filed: February 6, 2001 )  
For: NITRIDE SEMICONDUCTOR )  
LIGHT EMITTING DEVICE )

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**SUPPLEMENTAL PRELIMINARY AMENDMENT**

Assistant Commissioner for Patents  
Washington, D.C. 20231

Sir:

Prior to examination on the merits and calculation of claim fees, kindly amend the  
above-captioned application as follows:

**IN THE CLAIMS:**

Kindly add the following new claims 22 and 23.

--22. The nitride semiconductor light emitting device of claim 13, wherein the  
active layer is a III-V group nitride compound semiconductor layer having a multi-quantum  
well structure.

23. The nitride semiconductor light emitting device of claim 13, wherein the n-  
type clad layer has a thickness between 0.5  $\mu\text{m}$  and 1.7  $\mu\text{m}$ . --

REMARKS

In reviewing the file upon receiving the filing receipt, it was noted that claims 22 and 23 were inadvertently presented as claims 14 and 15. We regret any inconvenience this may have caused. Claims 22 and 23 are presented above. Please disregard the Preliminary Amendment of February 6, 2001. Prompt and favorable action on the merits are respectfully requested.

Respectfully submitted,

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